

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

PCT/DE97/02908

International Filing Date: 8 December 1997

Priority Date: 9 December 1996

Inventors: Lippert et al.

For: Silicon Germanium Hetero Bipolar Transistor and Method of
Making the Epitaxial Individual Layers of such a Transistor

86 Sparks Street
Cambridge, MA 02138-2216
8 June 1999

Hon.
Assistant Commissioner
for Patents
Box PCT
Washington, DC. 20231

Preliminary Amendment Prior Claims Fee Calculation

Sir:

With a view to putting the English translation of instant International Application as amended before the International Preliminary Examination Authority into formal compliance with current U.S. patent prosecution practice and to avoiding excess claims fees otherwise due, Applicants courteously request that the following amendment be entered.

In the Specification

Page 1, line 8: enter --BACKGROUND OF THE INVENTION.

1. Field of the Invention.--;

line 20: enter --2. The Prior Art.--;

page 2, line 32: enter --OBJECTS OF THE INVENTION.--;

page 3, line 21: enter --SUMMARY OF THE INVENTION.--;

page 5, line 16: enter --DESCRIPTION OF THE SEVERAL DRAWINGS.--;

line 25: enter --DETAILED DESCRIPTION OF PREFERRED
EMBODIMENTS.--;

page 9, line 1: change "Patent Claims." to --What is claimed is:--; and

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page 12, line 5: after "abstract" insert --of the Disclosure--.

In the Claims:

claim 3, line 2: cancel "1 or";

claim 4, line 2: change "one or more of the preceding claims" to --claim 1--;

claim 5, line 2: change "one or more of the preceding claims" to --claim 1--;

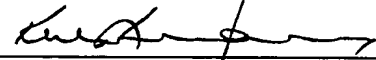
claim 10, line 1: change "one of claims 7 to" to --claim--;

claim 11, line 1: change "one or more of the claims 7 to" to --claim--;

claim 12, line 1: change "one or more of the claims 7 to" to --claim--; and

claim 13, line 1: change "one or more of the claims 7 to" to --claim--.

Respectfully submitted,



Karl Hormann
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